

Notice of References Cited

Application/Control No.

10/772,573

Applicant(s)/Patent Under
Reexamination
MAWST ET AL.

Examiner

Thomas L. Dickey

Art Unit

2826

Page 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	A	US-			
	B	US-			
	C	US-			
	D	US-			
	E	US-			
	F	US-			
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	O					
	P					
	Q					
	R					
	S					
	T					

NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Shan et al., "Band Anticrossing in GaInNAs Alloys," Phys. Rev. Lett. Vol. 82, No. 6, pp 1221-1224 (1999)
	V	Press Release, "Striking Effects Of Nitrogen In Semiconductor Alloy Explained," Lawrence Berkeley National Laboratory, June 9, 1999 (http://www.sciencedaily.com/releases/1999/06/990609072619.htm)
	W	
	X	

*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.